















ESD

TVS

MOS

LDO

Diode

Sensor

DC-DC

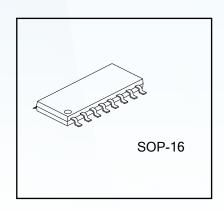
Product Specification

| Domestic Part Number | ST3232BDR |
|--|-----------|
| Overseas Part Number | ST3232BDR |
| ▶ Equivalent Part Number | ST3232BDR |





3.0V TO 5.5V LOW POWER MULTICHANNEL RS-232 LINE TRANSCEIVERS USING FOR 0.1 µF EXTERNAL CAPACITORS



DESCRIPTION

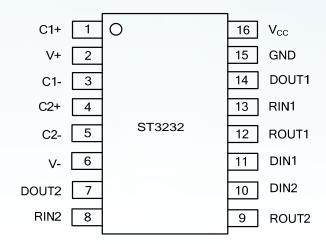
The ST3232BDR has two receivers and two drivers, and a dual charge-pump circuit. The device meets the requirements of TIA/EIA-232-F and provides the electrical interface between an asynchronous communication controller and the serial-port connector. The charge pump and four small external capacitors allow operation from a single 3.0V to 5.5V supply. The device operates at data signaling rates up to 250kbit/s and a maximum of $35V/\mu s$ driver output slew rate.

FEATURES

- * Exceeds ±8KV ESD Protection(HBM) for RS-232 I/O Pins
- * Meets the Requirements of TIA/EIA-232-F and ITU V.28 Standards
- * Operates With 3.0V to 5.5V V_{CC} Supply
- * Operates Up To 250kbit/s Data Rate
- * Two Drivers and Two Receivers
- * External Capacitors 4×0.1µF
- * Accepts 5.0V Logic Input With 3.3V Supply



PIN CONFIGURATION

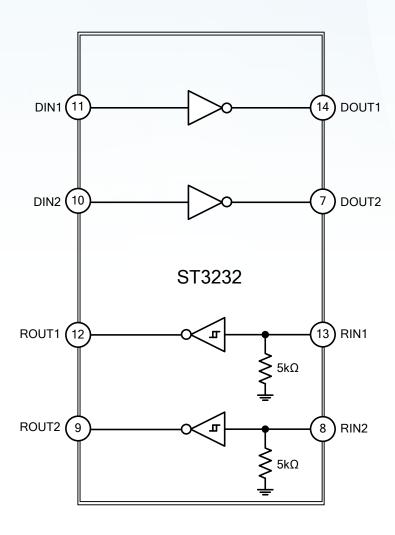


PIN DESCRIPTION

| PIN NO. | PIN NAME | DESCRIPTION | |
|---------|-----------------|--|--|
| 1 | C1+ | Positive Terminal of Voltage-Doubler Charge-Pump Capacitor | |
| 2 | V+ | +5.5V Generated by the Charge Pump | |
| 3 | C1- | Negative Terminal of Voltage-Doubler Charge-Pump Capacitor | |
| 4 | C2+ | Positive Terminal of Inverting Charge-Pump Capacitor | |
| 5 | C2- | Negative Terminal of Inverting Charge-Pump Capacitor | |
| 6 | V- | -5.5V Generated by the Charge Pump | |
| 7 | DOUT2 | RS-232 Driver Outputs | |
| 8 | RIN2 | RS-232 Receiver Inputs | |
| 9 | ROUT2 | TTL/CMOS Receiver Outputs | |
| 10 | DIN2 | TTL/CMOS Driver Inputs | |
| 11 | DIN1 | TTL/CMOS Driver Inputs | |
| 12 | ROUT1 | TTL/CMOS Receiver Outputs | |
| 13 | RIN1 | RS-232 Receiver Inputs | |
| 14 | DOUT1 | RS-232 Driver Outputs | |
| 15 | GND | Ground | |
| 16 | V _{CC} | +3.0V to +5.5V Supply Voltage | |



BLOCK DIAGRAM





ABSOLUTE MAXIMUM RATING [Over operating free-air temperature range (unless otherwise noted)]

| PARAMETER | | SYMBOL | RATINGS | UNIT |
|--|--------------|------------------|-----------------------------|------|
| Supply Voltage Range | | V_{CC} | -0.3 ~ +6.0 | V |
| Positive Output Supply Voltage Ran | ge (Note 2) | V+ | -0.3 ~ +7.0 | V |
| Negative Output Supply Voltage Ra | nge (Note 2) | V- | +0.3 ~ -7.0 | V |
| Supply Voltage Difference (Note 2) | | V+ - V- | +13 | V |
| Innut Valtage | Drivers | V | -0.3 ~ +6.0 | V |
| Input Voltage | Receivers | V_{IN} | -25 ~ +25 | V |
| Output Valtage | Drivers | M | -13.2 ~ +13.2 | V |
| Output Voltage | Receivers | V_{OUT} | -0.3 ~ V _{CC} +0.3 | V |
| Operating Virtual Junction Temperature | | T_J | +150 | °C |
| Storage Temperature | | T _{STG} | -65 ~ + 150 | °C |

Notes: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

THERMAL DATA

| PARAMETER | | SYMBOL | RATING | UNIT |
|---------------------|--------|-----------------|--------|------|
| Junction to Ambient | SOP-16 | θ _{JA} | 105 | °C/W |

RECOMMENDED OPERATING CONDITIONS (See Note & Table 1)

| PARAMETER | SYMBOL | TEST CONDITIONS | | MIN | TYP | MAX | UNIT |
|--|-----------------|-----------------------|-----------------------|-----|-----|-----|------|
| Supply Voltage | | V _{CC} =3.3V | | 3.0 | 3.3 | 3.6 | V |
| Supply Voltage | V _{CC} | V _{CC} =5.0V | | 4.5 | 5.0 | 5.5 | V |
| Driver and Control High-level Input | V DIN | DIN | V_{CC} =3.3 V | 2.0 | | | V |
| Voltage | V_{IH} | DIN | V _{CC} =5.5V | 2.4 | | | V |
| Driver and Control Low-level Input Voltage | V_{IL} | DIN | | | | 0.8 | V |
| Driver and Control Input Voltage | V_{IN} | DIN | | | | 5.5 | V |
| Receiver Input Voltage | V_{RIN} | | • | -25 | | 25 | V |
| Operating Free-Air Temperature | T_A | | | 0 | | 70 | °C |

Notes: Test conditions are C1~C4=0.1 μ F at V_{CC}=3.3V±0.3V; C1=0.047 μ F, C2~C4=0.33 μ F at V_{CC}=5.0V±0.5V.

^{2.} All voltages are with respect to network GND.



ELECTRICAL CHARACTERISTICS [(over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Note 3 & Table 1)]

| PARAMETER | SYMBOL | TEST CONDITIONS | MIN | TYP (Note 1) | MAX | UNIT |
|--------------------------------|-----------------|--|-----------------------|------------------------|-----|------|
| Supply Current | I _{CC} | No load | | 0.3 | 1.0 | mA |
| DRIVER SECTION | | | | | | |
| High-Level Output Voltage | V_{OH} | DOUT at R_L =3k Ω to GND, DIN=GND | +5.0 | +5.4 | | V |
| Low-Level Output Voltage | V_{OL} | DOUT at R_L =3k Ω to GND, DIN= V_{CC} | -5.0 | -5.4 | | V |
| High-Level Input Current | I _{OH} | $V_I = V_{CC}$ | | ±0.01 | ±1 | μΑ |
| Low-Level Input Current | I_{OL} | V₁ at GND | | ±0.01 | ±1 | μΑ |
| Short-Circuit Output Current | | V_{CC} =3.6V, V_{OUT} =0V | | ±35 | ±60 | mA |
| (Note 2) | los | V _{CC} =5.5V, V _{OUT} =0V | | ±35 | ±60 | mA |
| Output Resistance | r_{O} | V _{CC} , V+ and V- =0V, V _{OUT} =±2.0V | 300 | 10M | | Ω |
| RECEIVER SECTION | | | | | | |
| High-Level Output Voltage | V_{OH} | I _{OH} =-1.0mA | V _{CC} -0.6V | V _{CC} - 0.1V | | V |
| Low-Level Output Voltage | V_{OL} | I _{OL} =1.6mA | | | 0.4 | V |
| Positive-Going Input Threshold | V | V _{CC} =3.3V | | 1.5 | 2.4 | V |
| Voltage | V_{IT+} | V _{CC} =5.0V | | 1.8 | 2.4 | V |
| Negative-Going Input | \/ | V _{CC} =3.3V | 0.6 | 1.2 | | V |
| Threshold Voltage | V_{IT} | V _{CC} =5.0V | 0.8 | 1.5 | | V |
| Input Hysteresis | V_{HYS} | $V_{IT+} \sim V_{IT-}$ | | 0.3 | | V |
| Input Resistance | R_{l} | V _I =±3.0V~±25V | 3 | 5 | 7 | kΩ |

Notes: 1. All typical values are at V_{CC} =3.3V or V_{CC} =5.0V, and T_A =25°C.

- 2. Short-circuit durations should be controlled to prevent exceeding the device absolute power-dissipation ratings, and not more than one output should be shorted at a time.
- 3. Test conditions are C1~C4=0.1 μ F at V_{CC}=3.3V±0.3V; C1=0.047 μ F, C2~C4=0.33 μ F at V_{CC}=5.0V±0.5V.
- 4. Pulse skew is defined as |t_{PLH}-t_{PHL}| of each channel of the same device.

SWITCHING CHARACTERISTICS [over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Note 3 and Table 1)]

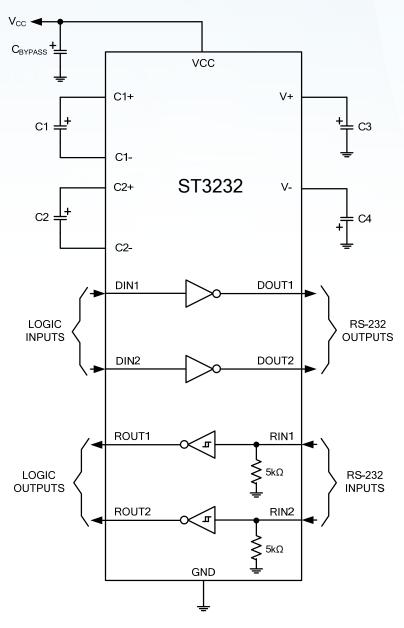
| PARAMETER | SYMBOL | TEST CONDITIONS | | MIN | TYP (Note 1) | MAX | UNIT |
|--|--------------------|---|------------------------------|-----|-----------------|-----|--------|
| DRIVER SECTION | | | | | | | |
| Maximum Data Rate | | C_L =1000pF, R_L =3k Ω , One Driver Switching | | 120 | | 250 | Kbit/s |
| Pulse Skew (Note 4) | t _{SK(p)} | C _L =220pF~250 | 0pF, R _L =3kΩ~7kΩ | | 300 | | ns |
| Slew Rate, Transition Region | | $R_L = 3k\Omega \sim 7k\Omega$, | C _L =220pF~1000pF | 5 | | 35 | V/µs |
| Siew Rate, Transition Region | | V _{CC} =3.3V | C _L =220pF~2500pF | 3 | | 35 | ν/μ5 |
| RECEIVER SECTION | _ | | | | | | - |
| Propagation Delay Time, Low-to High-Level Output | t _{PLH} | C _L =150pF | | | 300 | | ns |
| Propagation Delay Time, Highto Low-Level Output | t _{PHL} | C _L =150pF | | | 300 | | ns |
| Output Enable Time | t _{EN} | $C_L=150pF, R_L=3k\Omega$ | | | 200 | | ns |
| Output Disable Time | t _{DIS} | $C_L=150pF, R_L=3k\Omega$ | | | 200 | | ns |
| Pulse Skew (Note 4) | t _{SK(P)} | t _{PLH} -t _{PHL} | _ | | 300 | | ns |

Notes: 1. All typical values are at V_{CC} =3.3V or V_{CC} =5.0V, and T_A =25°C.

- 2. Short-circuit durations should be controlled to prevent exceeding the device absolute power-dissipation ratings, and not more than one output should be shorted at a time.
- 3. Test conditions are C1~C4=0.1 μ F at V_{CC}=3.3V±0.3V; C1=0.047 μ F, C2~C4=0.33 μ F at V_{CC}=5.0V±0.5V.
- 4. Pulse skew is defined as |tplh-tphl| of each channel of the same device.



TYPICAL APPLICATION CIRCUIT



Notes: 1. C3 can be connected to V_{CC} or GND. 2. Resistor values shown are nominal. 3. NC: No internal connection.

- 4. Nonpolarized ceramic capacitors are acceptable. If polarized tantalum or electrolytic capacitors are used, they should be connected as shown.

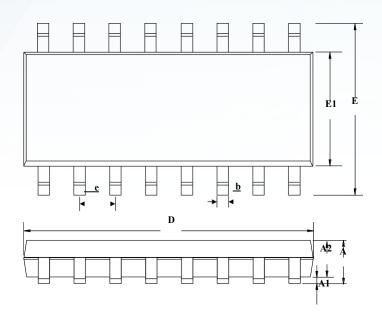
Table 1. Typical Operating Circuit and Capacitor Values

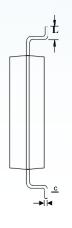
| V _{CC} (V) | C1 (µF) | C2, C3, C4 (µF) | C _{BYPASS} (µF) |
|---------------------|---------|-----------------|--------------------------|
| 3.0~3.6 | 0.22 | 0.22 | 0.22 |
| 3.15~3.6 | 0.1 | 0.1 | 0.1 |
| 4.5~5.5 | 0.047 | 0.33 | 0.047 |
| 3.0~5.5 | 0.22 | 1.0 | 0.22 |



PACKAGE: SOP-16

UNIT: mm





| SYMBOL | MILLIMETER | | | |
|-----------|------------|------|-------|--|
| 3 I MIBOL | MIN | NOM | MAX | |
| A | _ | | 1.80 | |
| A1 | 0.10 | 0.15 | 0.25 | |
| A2 | 1.25 | 1.45 | 1.65 | |
| ь | 0.33 | _ | 0.51 | |
| с | 0.17 | _ | 0.25 | |
| D | 9.50 | _ | 10.20 | |
| Е | 5.80 | 6.00 | 6.20 | |
| E1 | 3.70 | _ | 4.10 | |
| e | 1.27BSC | | | |
| L | 0.45 | 0.80 | | |

ORDERING INFORMATION

| Ordering Number | Package | Baseqty | Packing |
|-----------------|---------|---------|---------------|
| ST3232BDR | SOP-16 | 2500 | Tape and reel |



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